# 1 Objective

N/A

# 2 Experimental Procedures

## 2.1 Semiconductor Measurements

First we went over and measured the physical dimensions of the germanium sample we used for the lab. Since the germanium sample was in a tube and already hooked up to the ohm meter, we turned on the ohm meter and first measured the resistance at room temperature. Make sure you are using the right scale for the ohmmeter; if it is just reading out '1' then the scale is wrong and needs to be changed. Place the sample into the bucket of water and also place the thermostat into the water as well. Place the bucket on the stove/heater device and turn on the heater. Now we made measurements roughly every 10°C from 23°C to 100°C.
Once we had all our measurements using the heater, we dumped out the warm water. We then grabbed a bucket of ice water and placed our sample as well as our thermostat in the ice. This bucket should be at 0°C. Record the resistance. Next we placed our sample into the solid ice bucket. This bucket should be at a temperature of roughly -73°C. Again, we recorded the resistance.

## 2.2 Metal Measurements

Measure the diameter and length of all the samples, the length is measured as the distance between the inner solders points. Place samples in beaker of water on hot plate. Get temperature of water with test subjects in beaker to and record resistance readings of all 5 samples. Remove beaker from hot plate and place on thermocouple's stand base. Lower temperature of water in beaker by adding ice cubes. Record resistance of all 5 samples every drop below until reaching room temperature. Add ice into beaker until temperature reaches and record resistance. Place samples in dry ice bucket, let them sit for a minute, and record resistance of samples. Place samples in liquid nitrogen bucket, let them sit for a minute, and record resistance of samples.

## 2.3 Salt (NaCl) Measurements

The setup was already done for us. The salt sample had electrodes hooked up and was already in the furnace. We first preheated to 750°C and then turned off the furnace. We took measurements every 50°C as the sample cooled down to 400°C. The way we took measurements is we first used the dial at the top right of the machine to tune to the correct scale. Next we tuned the larger dial at the bottom right of the machine for a finer measurements. We tuned this dial until the arrow in the middle of the machine was pointing to 0. To get a measurement we took the value of the large dial on the bottom right and multiplied it by the correct scaling factor used by the dial on the top right.

# 3 Experimental Results

| Temperature (K) | 77 | 200 | 273 | 305 | 310 | 328 | 339 | 358 | 368 |
|---|---|---|---|---|---|---|---|---|---|
| Sample 11 ($\Omega$) | 0.000246 | 0.000470 | 0.000593 | 0.000634 | 0.000663 | 0.000695 | 0.000716 | 0.000753 | 0.000787 |
| Sample 12 ($\Omega$) | 0.000356 | 0.000690 | 0.000755 | 0.000796 | 0.000832 | 0.000867 | 0.000877 | 0.000923 | 0.001000 |
| Sample 13 ($\Omega$) | 0.000243 | 0.000375 | 0.000419 | 0.000435 | 0.000442 | 0.000463 | 0.000466 | 0.000487 | 0.000503 |
| Sample 14 ($\Omega$) | 0.00113 | 0.00157 | 0.00176 | 0.00183 | 0.00185 | 0.00192 | 0.00195 | 0.00196 | 0.00205 |
| Sample 15 ($\Omega$) | 0.000571 | 0.00147 | 0.00130 | 0.00165 | 0.00141 | 0.00182 | 0.00179 | 0.00185 | 0.00186 |

Figure 1: Data collected for metal samples during heating. Data take from fellow lab partners [3]
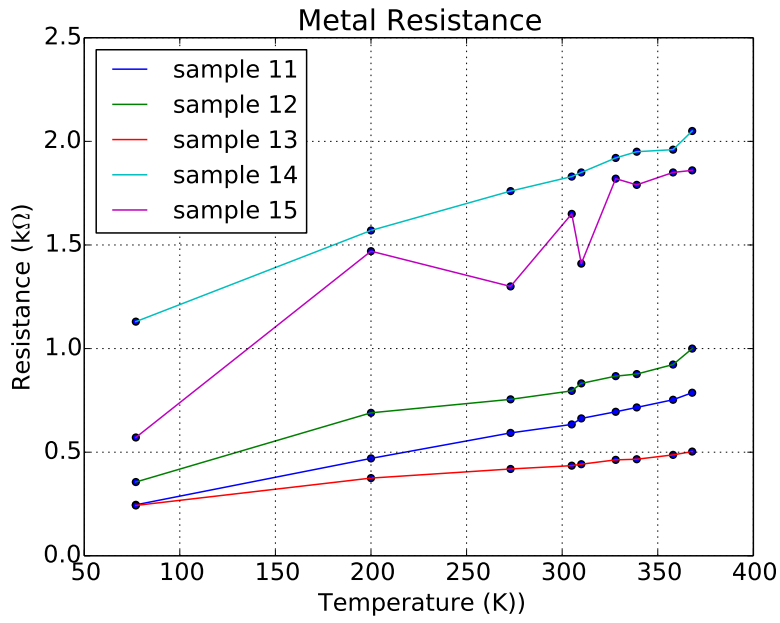
Figure 2: Plot of the data points for metal measurements

| Temperature (°C) | -73 | 0 | 23 | 35 | 44 | 53 | 64 | 73 | 83 | 95 | 100 |
|---|---|---|---|---|---|---|---|---|---|---|---|
| Resistance kΩ | 228 | 9.70 | 3.55 | 2.45 | 1.61 | 1.13 | 0.70 | 0.50 | 0.35 | 0.24 | 0.20 |

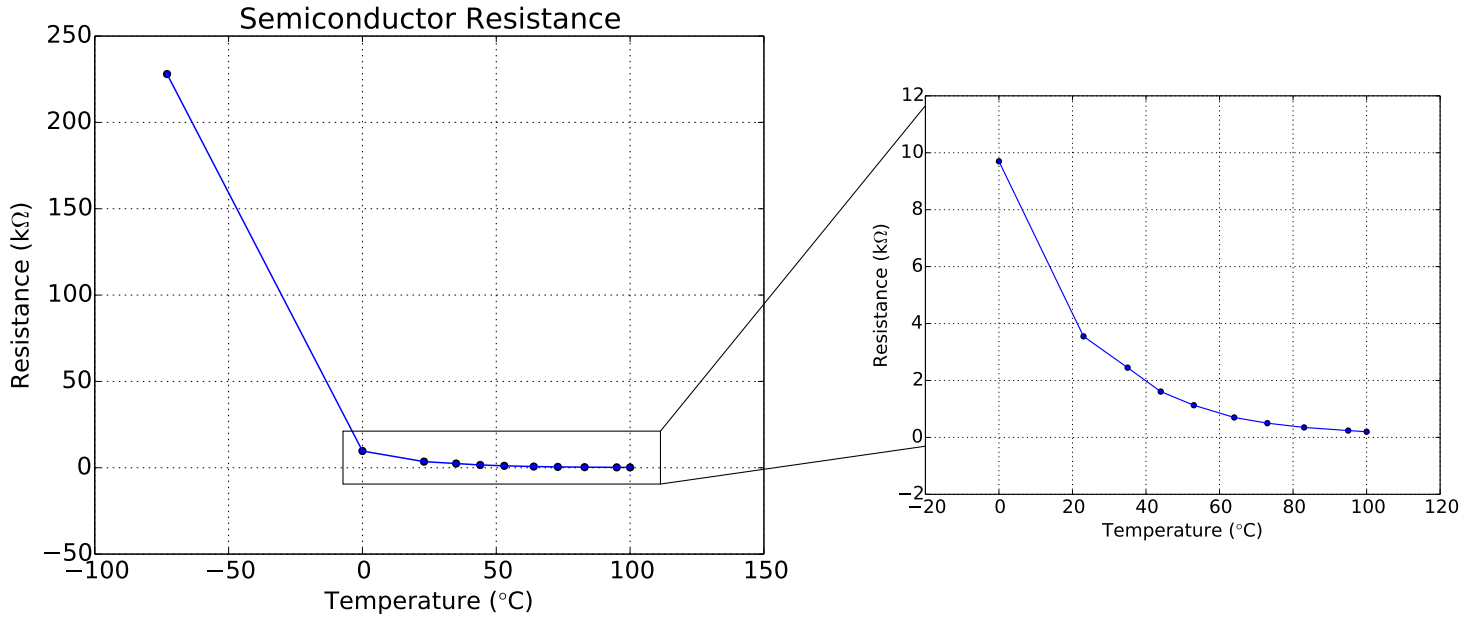Figure 3: Data recorded for semiconductor (Germanium) heating and resistance measurements



Figure 4: Plot of the data for Semiconductor heating

| Temperature (°C) | 400 | 450 | 500 | 550 | 600 | 650 | 700 | 750 |
|---|---|---|---|---|---|---|---|---|
| Resistance kΩ | $4.6 \times 10^2$ | $2.1 \times 10^2$ | $9.2 \times 10^1$ | $4.35 \times 10^1$ | $1.64 \times 10^1$ | 6.3 | 2.3 | 0.85 |

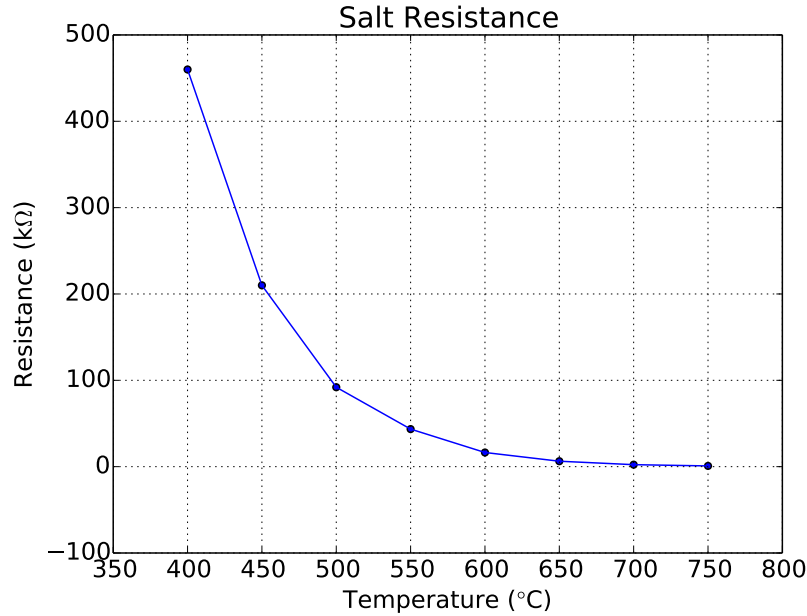Figure 5: Temperatures and Resistances measured for the salt (NaCl) sample.



Figure 6: Plot of data for salt measurements

# 4    Discussion

**1) Rank the five (5) specimens in order of purity, and specify $\rho_r$ for each specimen in micro-ohm-cm.**
Using the equation to calculate resistivity on page 3 of the lab manual [2] and picking $T_1 = 77K$ and $T_2 = 273K$, we get the following results,

| Purity | Sample | $\rho_r$ ($\mu\Omega$-cm) |
|---|---|---|
| 1 | sample 11 | 0.766 |
| 2 | sample 15 | 0.866 |
| 3 | sample 12 | 1.01 |
| 4 | sample 13 | 1.68 |
| 5 | sample 14 | 2.24 |

Figure 7: Purity rank from highest purity to lowest. i.e. 1 is most pure and 5 is least pure.

**2) To what precision can you verify Matthiessen's rule? To answer this question, consider how the resistivity changes with temperature for a fixed concentration of impurities, then how the resistivity changes with impurity concentration when the temperature is fixed.**
N/A

**3) Would you expect $\rho$ to increase or decrease as T is increased through the melting point? Why?**
The resistivity will increase. This is because it is much harder for electrons to move through a material in the liquid phase rather than a solid phase. In the liquid phase, atoms move around a lot, and as a result, hinder the effectiveness of the electrons to make it across a material without running into something.

**4) If you dope a metal A with another metal B where $\rho_B < \rho_A$, do you expect the resistivity of the alloy to increase or decrease? Why?**
N/A

**5) Plot ln (G) versus 1/T for the semiconducting sample studied in this lab.**

Note the y axis units here. In the lab manual $\ln G$ was plotted with units of $\Omega^{-1}m^{-1}$. However, as we all know you cannot take a natural log of a number that has units because there is no physical meaning behind it; natural logs can only be used with unitless numbers. So I have added a constant. Instead we are plotting $\ln G/G_0$ where $G_0 = 1$ and has the same units as $G$. Thus there should be no units on the y axis of this plot.
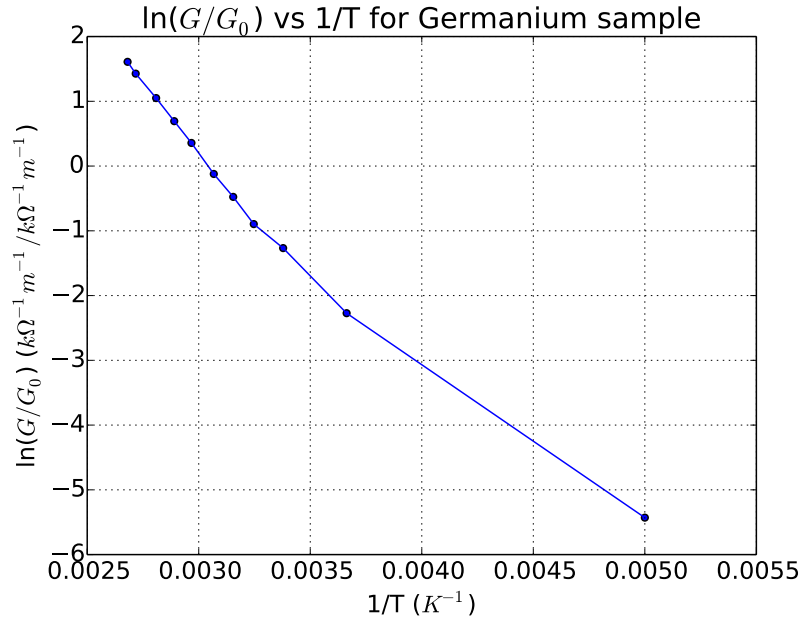


Figure 8: Plot of the natural log of conductance vs inverse temperature for a Germanium semiconductor

**6) Over what temperature range, if any, does your sample behave as an intrinsic semiconductor?**

Looking at the plot above, the germanium sample does behave like an intrinsic semiconductor at temperatures higher than about room temperature. At cold temperatures of $0°C$ and $-73°C$ the sample tends to lose its intrinsic semiconductor behavior. However at temperatures from $23°C$ to $100°C$ the sample does show intrinsic semiconductor behavior.

**7) What is the energy gap for your sample? Compare with published literature values and cite your sources.**

According to [4], the energy band gap for Germanium is 0.67 eV (at 302K). According to the lab manual [2], the slope of figure 8 should be $-E_g/2k$. Therefore $E_g = -2k$(slope) where k is boltzmann's constant. Using linear regression and fitting a line to the data in the intrinsic in figure 8, a slope of $-4.42 \times 10^3 K^{-1}$ was calculated with a R value of 0.9997. This corresponds to an $E_g = 0.77$eV. This corresponds to a percent error of 15%.

**8) Predict the resistance at 150°C of your sample.**

After doing a linear fit on the plot in figure 8, the slope and intercept were calculated to be -3.05×10⁴ and 9.371. Using this data we find that:

$$y = mx + b = \frac{-4.42 \times 10^3}{150°C + 273} + 9.371 = -1.08$$

We also know from figure 8 that the y axis corresponds to $\ln G/G_0$ where $G_0 = 1$.

$$y = \ln G/G_0 \Rightarrow -1.08 = lnG/G_0 \Rightarrow e^{-1.08} = \frac{G}{G_0} \Rightarrow G = 0.340 \Rightarrow R = 1/G = 2.94\text{k}\Omega.$$

**9) Plot ln (G) versus 1/T for the insulator sample studied in this lab.**
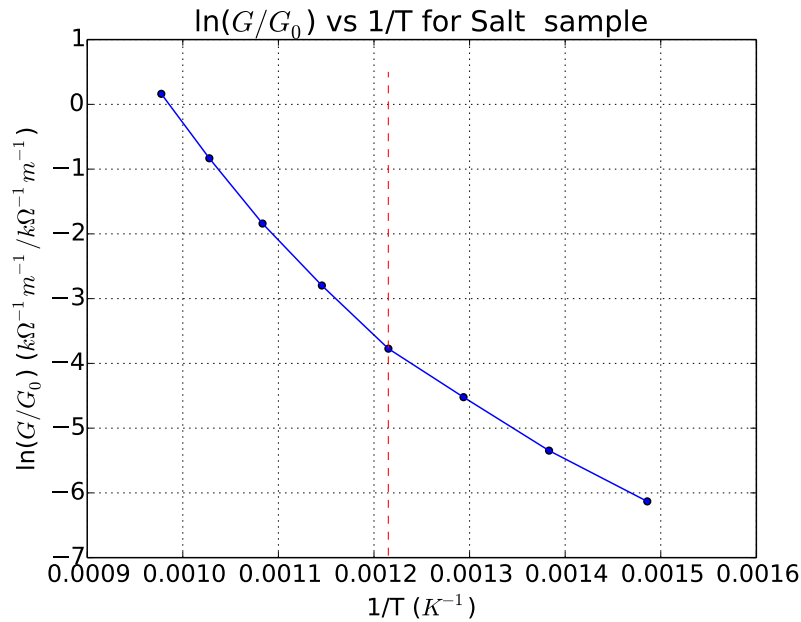
See below plot.

Figure 9: Plot of the natural log of conductance vs inverse temperature for salt (NaCl). Dashed red line indicates a change in slope

10) **What is the temperature corresponding to the change in slope of the ln (G) vs 1/T plot? If you don't observe any change in slope, what does that mean?**
Looking at figure 9 the slope change occurs roughly in the middle of the graph as indicated by the red line. This corresponds to a temperature of 550°C.

11) **From your plot determine both $E_m$ and $W$ in eV.**
From the lab manual [2] we know that the slope on the upper part of the graph in figure 9 should be equal to $-(E_m + [W/2])/k$ and the slope on the bottom part of the graph is equal to $-E_m/k$ where $k$ is boltmann's constant. Using linear regression on both parts of the plot in figure 9, slopes of -8.73×$10^4 K^{-1}$ and -1.76×$10^5 K^{-1}$ were calculated.

$$E_m = -\frac{\text{slope}}{k} = -\frac{-8.73 \times 10^4}{1.38 \times 10^{-23}} = 6.33 \times 10^{27} \text{J} =$$
$$W = -2(\text{slope} * k + E_m) = -2(-1.76 \times 10^5 * 1.38 \times 10^{-23} + 6.33 \times 10^{27}) = 1.27 \times 10^{28} \text{J} =$$

12) **Do you think that conductivity measurements could be used as an index of purity in ionic crystals? Discuss.**
N/A

# 5    Conclusions

As a result of this investigation, the following conclusions can be drawn.

1. N/A

# 6    References

1. James F. Shackelford, Introduction to Materials Science for Engineers, Seventh Edition, Pearson Higher Education, Inc., Upper Saddle River, New Jersey (2009).

2. Gronsky, Ron. Lab 06 Manual: Electronic Properties of Materials. Berkeley: Ronald Gronsky, 2014. Web.

3. Justin Chen and Sarah Hull. E45. Lab sec 103.

4. Streetman, Ben G.; Sanjay Banerjee (2000). Solid State electronic Devices (5th ed.). New Jersey: Prentice Hall. p. 524. ISBN 0-13-025538-6.